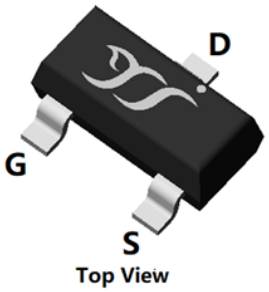
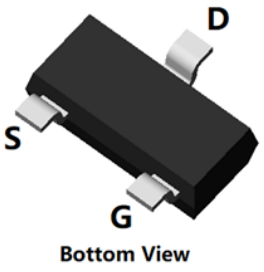
N-Channel Enhancement Mode Field Effect Transistor

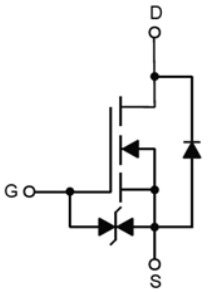


Top View



Bottom View

SOT-23



Product Summary

- V_{DS} 60V
- I_D 2.3A
- $R_{DS(ON)}$(at V_{GS}=10V) ＜94mΩ
- $R_{DS(ON)}$(at V_{GS}=4.5V) ＜126mΩ
- ESD protected up to 1.0KV (HBM)

General Description

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Moisture Sensitivity Level 1
- Epoxy Meets UL 94 V-0 Flammability Rating
- Part no. with suffix “Q” means AEC-Q101 qualified
- Halogen Free

Applications

- Relay driver
- High-speed line driver
- Low-side load switch
- Switching circuits

■ Limiting Values

Parameter	Conditions		Symbol	Min	Max	Unit
Drain-source Voltage			V_{DS}	-	60	V
Gate-source Voltage			V_{GS}	-20	20	
Continuous Drain Current (Note 1,2)	Steady-State	T_A=25℃,V_{GS}=10V	I_D	-	2.3	A
		T_A=100℃,V_{GS}=10V		-	1.5	
Pulsed Drain Current	T_A=25℃,t_p≤10μs		I_{DM}	-	18.4	
Maximum Body-Diode Continuous Current	T_A=25℃		I_S	-	2.3	
Total Power Dissipation (Note 1,2)	Steady-State	T_A=25℃	P_D	-	1.1	W
		T_A=100℃		-	0.4	
Junction and Storage Temperature Range			T_J , T_{STG}	-55	150	℃

■Thermal Resistance

Parameter		Symbol	Typ	Max	Units
Thermal Resistance Junction-to-Ambient (Note 2)	Steady-State	$R_{\theta JA}$		116	℃/W

■ Ordering Information (Example)

PREFERED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
YJL094N06AJKQ	F2	094N06	3000	30000	120000	7“ reel

■ Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V,I_D=250μA,Tj=25℃	60	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=60V,V_{GS}=0V,Tj=25℃	-	-	1	μA
		V_{DS}=60V,V_{GS}=0V,Tj=150℃	-	-	100	μA
Gate-Source Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V,Tj=25℃	-	-	±10	μA
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=250μA,Tj=25℃	1.1	1.6	2.1	V
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V_{GS}=10V,I_D=2A,Tj=25℃	-	74	94	mΩ
		V_{GS}=4.5V,I_D=1A,Tj=25℃	-	84	126	mΩ
Diode Forward Voltage	V_{SD}	I_S=2A,V_{GS}=0V,Tj=25℃	-	0.82	1.2	V
Gate Resistance	R_G	f=1MHz,Tj=25℃	-	6	-	Ω
Dynamic Parameters						
Input Capacitance	C_{iss}	V_{DS}=30V,V_{GS}=0V,f=1MHz,Tj=25℃	-	316	-	pF
Output Capacitance	C_{oss}		-	21	-	
Reverse Transfer Capacitance	C_{rss}		-	16	-	
Switching Parameters						
Total Gate Charge	Q_g	V_{GS}=10V,V_{DS}=30V,I_D=2A,Tj=25℃	-	6.6	-	nC
Gate-Source Charge	Q_{gs}		-	1.1	-	
Gate-Drain Charge	Q_{gd}		-	1.4	-	
Reverse Recovery Charge	Q_{rr}	I_F=2A,di/dt=100A/μs,V_{GS}=0V, V_R=30V,Tj =25℃	-	8	-	nC
Reverse Recovery Time	t_{rr}		-	12.8	-	ns
Turn-on Delay Time	$t_{D(on)}$	V_{GS}=10V,V_{DS}=30V,I_D=2A, R_{GEN}=3Ω, Tj =25℃	-	4.6	-	ns
Turn-on Rise Time	t_r		-	2.6	-	
Turn-off Delay Time	$t_{D(off)}$		-	14.3	-	
Turn-off Fall Time	t_f		-	2.7	-	

Note：

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.
2. The value of $R_{\theta JA}$ is measured with the device mounted on the 40mm*40mm*1.1mm single layer FR-4 PCB board with 1 in^2 pad of 2oz. Copper, in the still air environment with T_A=25℃.The maximum allowed junction temperature of 150℃. The value in any given application depends on the user's specific board design.

■Typical Electrical and Thermal Characteristics Diagrams

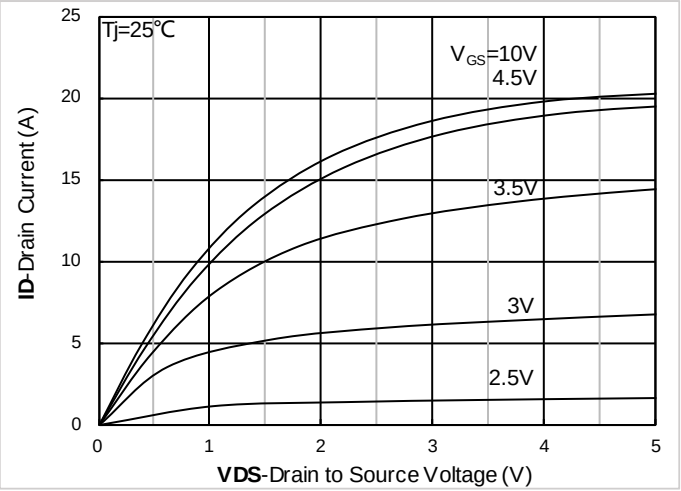


Figure 1. Output Characteristics; typical values

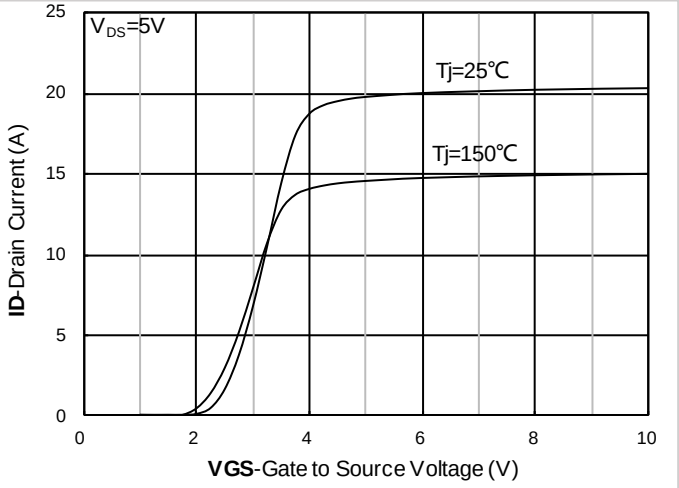


Figure 2. Transfer Characteristics; typical values

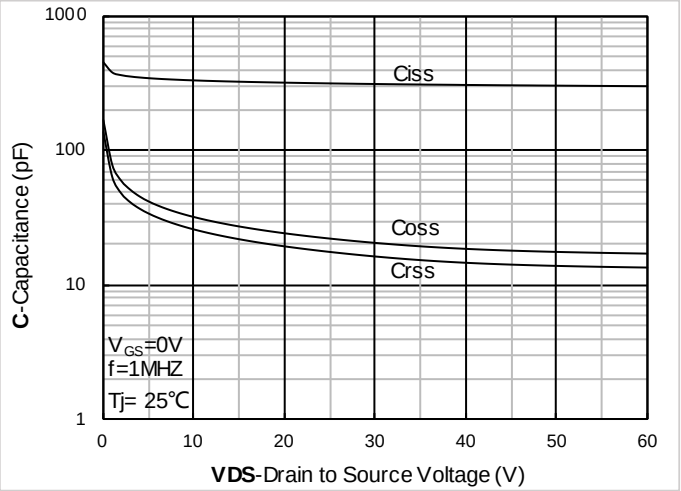


Figure 3. Capacitance Characteristics; typical values

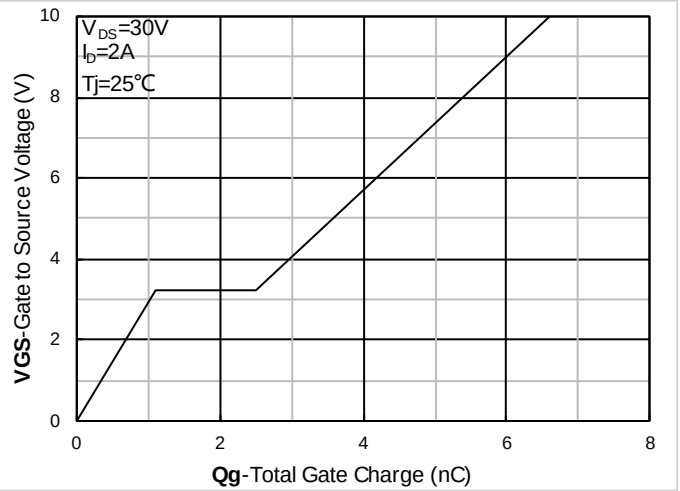


Figure 4. Gate Charge; typical values

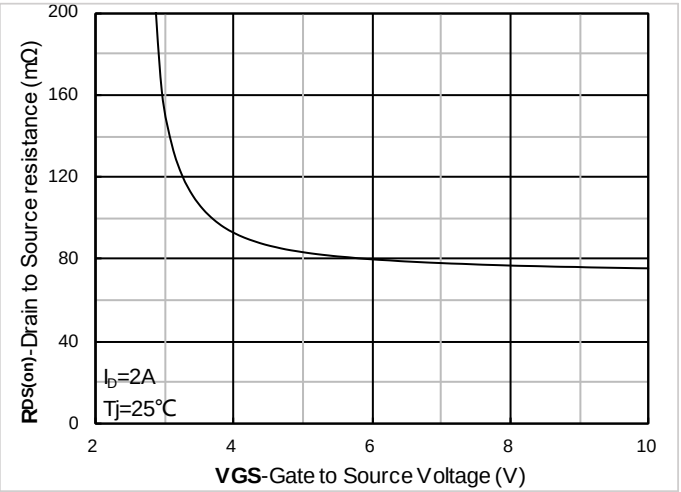


Figure 5. On-Resistance vs. Gate to Source Voltage; typical values

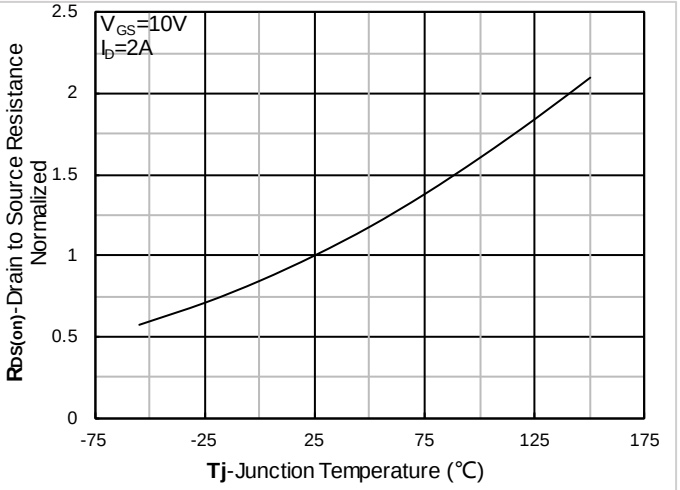


Figure 6. Normalized On-Resistance

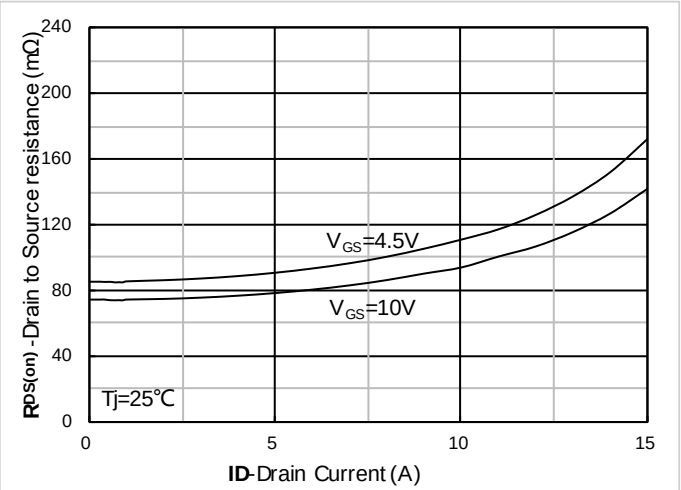


Figure 7. $R_{DS(on)}$ vs. Drain Current; typical values

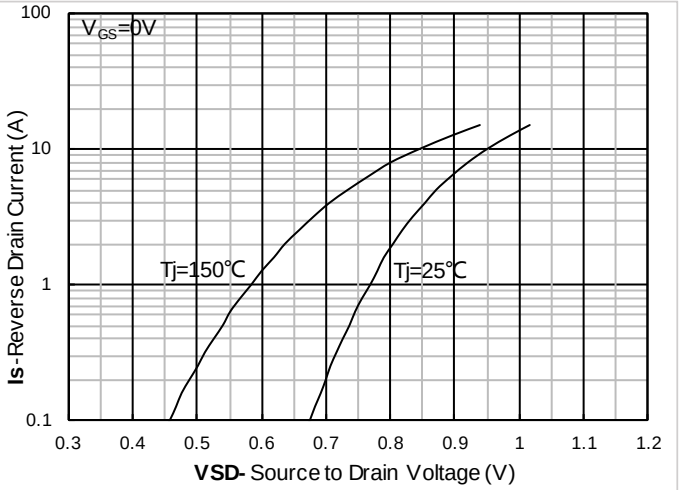


Figure 8. Forward characteristics of reverse diode; typical values

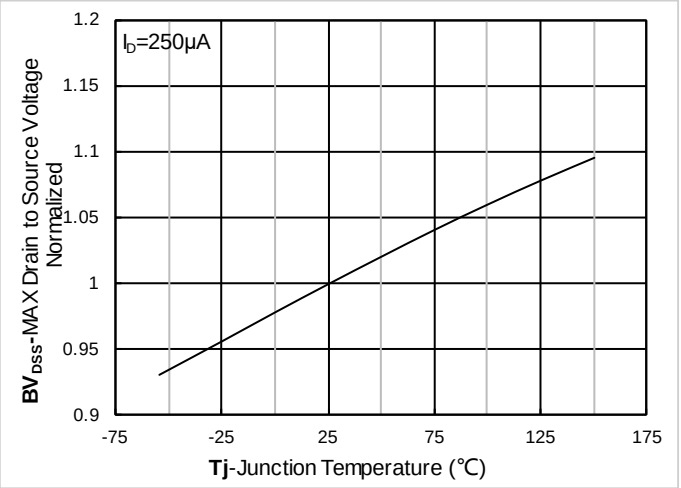


Figure 9. Normalized breakdown voltage

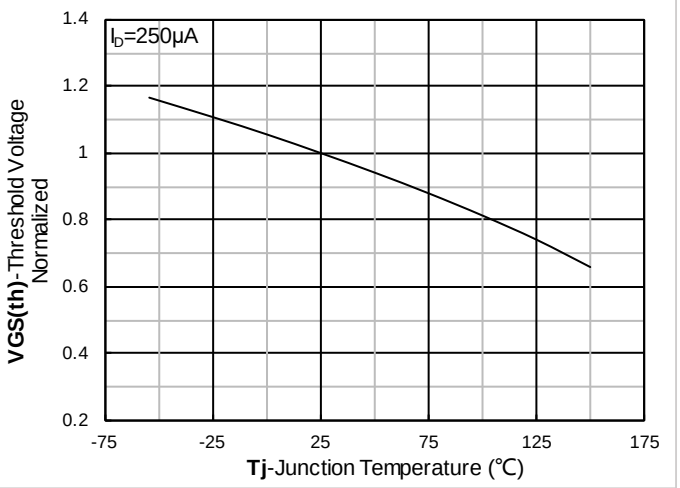


Figure 10. Normalized Threshold voltage

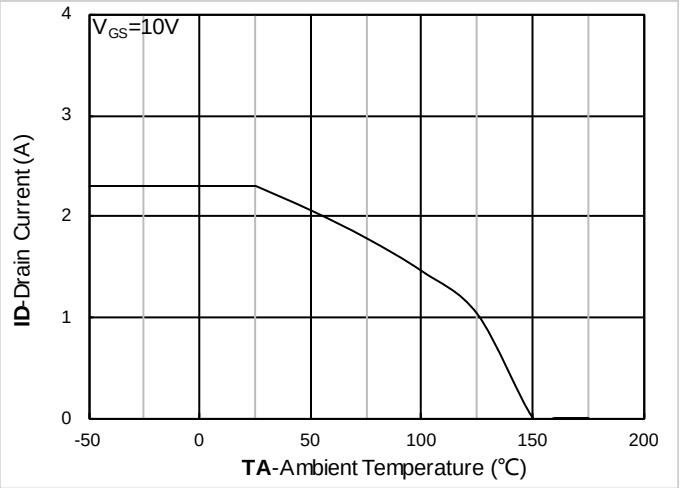


Figure 11. Current dissipation

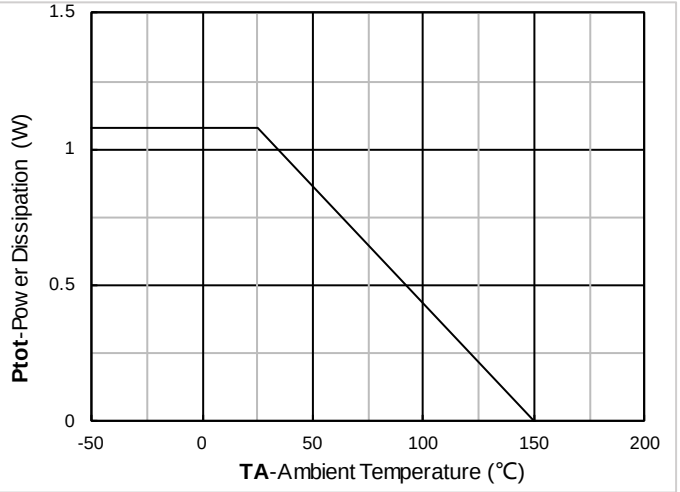


Figure 12. Power dissipation

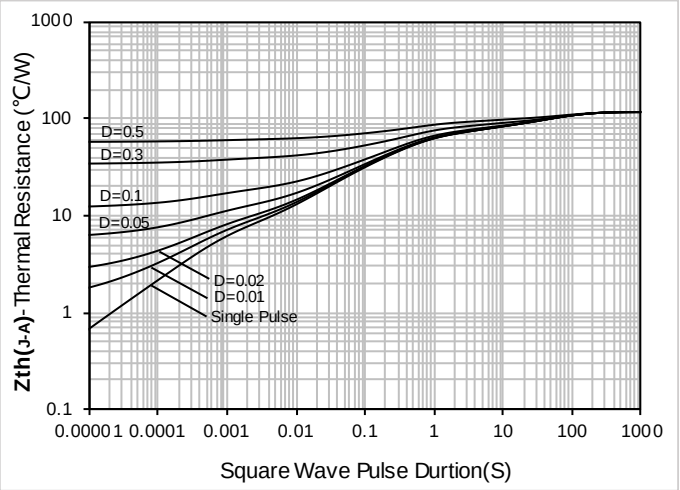


Figure 13. Maximum Transient Thermal Impedance

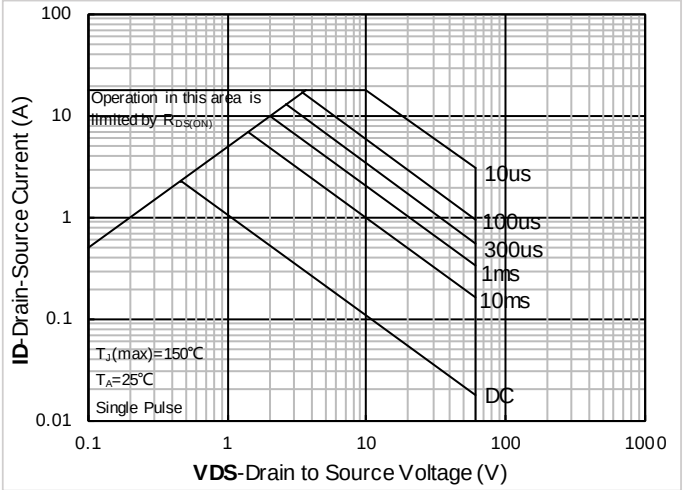
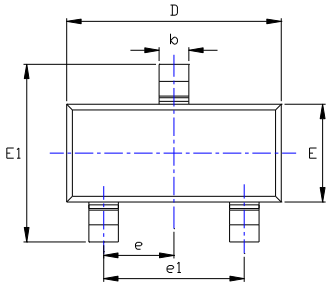
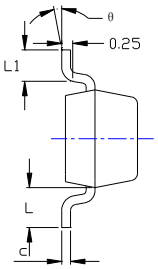


Figure 14. Safe Operation Area

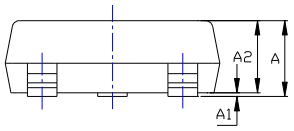
■ SOT-23 Package Information



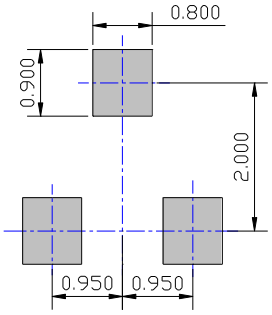
TOP VIEW



SIDE VIEW



SIDE VIEW



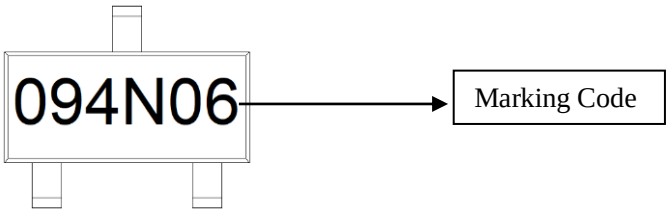
UNIT：mm

SUGGESTED SOLDER PAD LAYOUT

DIMENSIONS				
SYMBOL	INCHES		Millimeter	
	MIN.	MAX.	MIN.	MAX.
A	0.035	0.045	0.900	1.150
A1	0.000	0.004	0.000	0.100
A2	0.035	0.041	0.900	1.050
b	0.012	0.020	0.300	0.500
c	0.004	0.008	0.100	0.200
D	0.110	0.118	2.800	3.000
E	0.047	0.055	1.200	1.400
E1	0.089	0.100	2.250	2.550
e	0.037TYP		0.950TYP	
e1	0.071	0.079	1.800	2.000
L	0.022REF		0.550REF	
L1	0.012	0.020	0.300	0.500
θ	0°	8°	0°	8°

NOTE:
1.PACKAGE BODY SIZES EXCLUDE MOLD FLASH AND GATE BURRS.
2.TOLERANCE 0.1mm UNLESS OTHERWISE SPECIFIED.
3.THE PAD LAYOUT IS FOR REFERENCE PURPOSES ONLY.

■ Marking Information



Note：
1. All marking is at middle of the product body
2. All marking is in laser printing
3. 094N06 is marking code
4. Body color: Black

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